

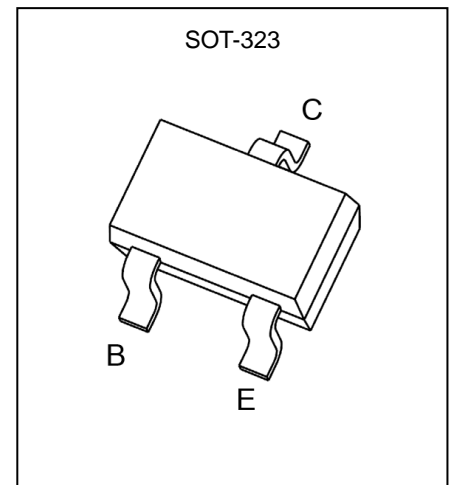


MMST3904 Transistor(NPN)

Feature

- Epitaxial planar die construction

Marking: K2N



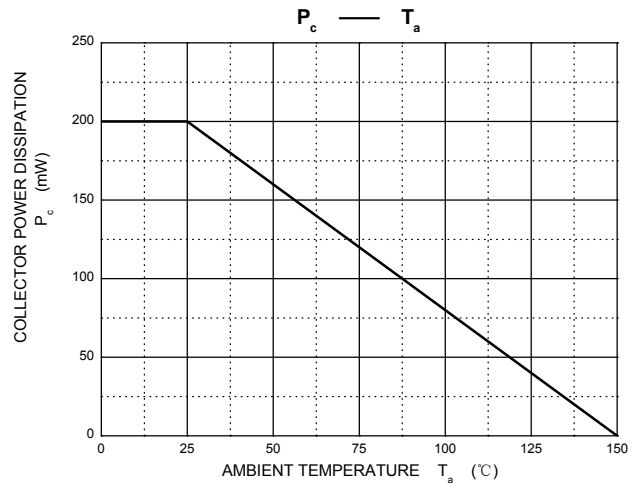
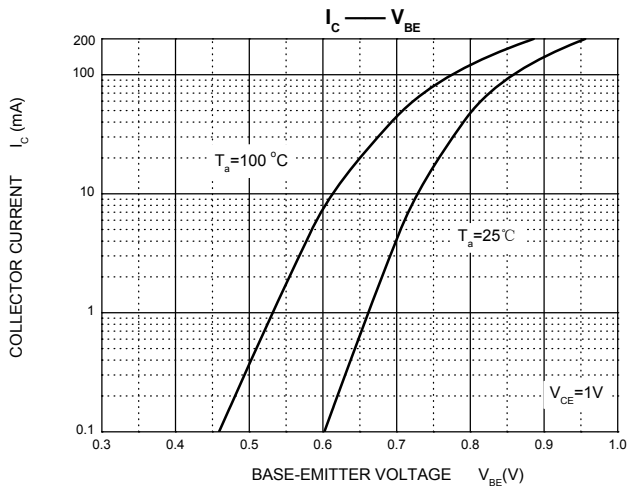
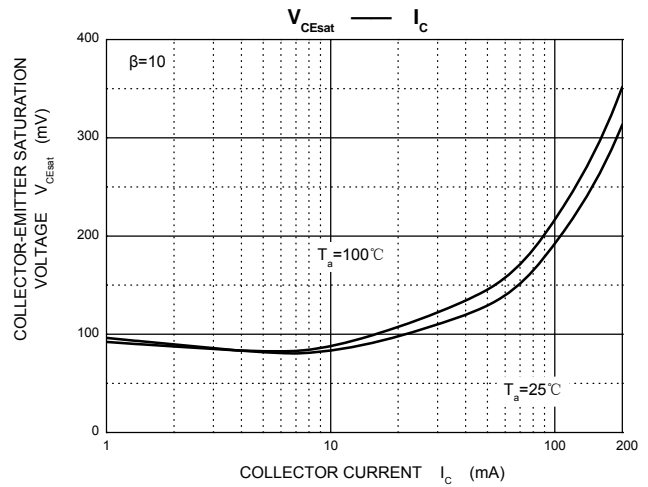
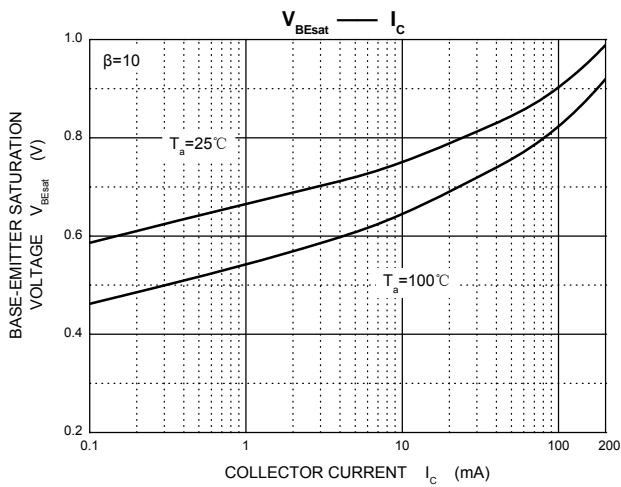
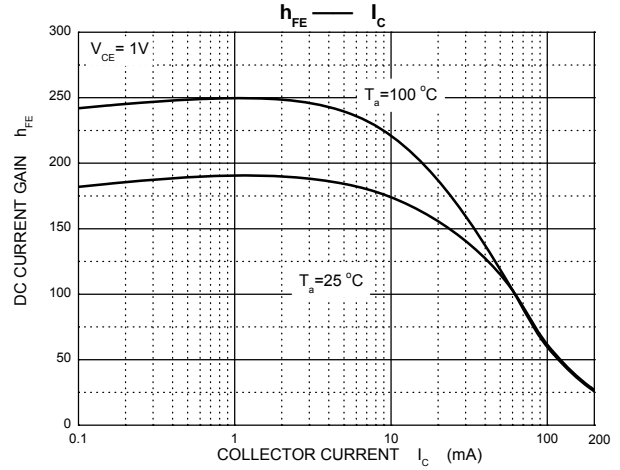
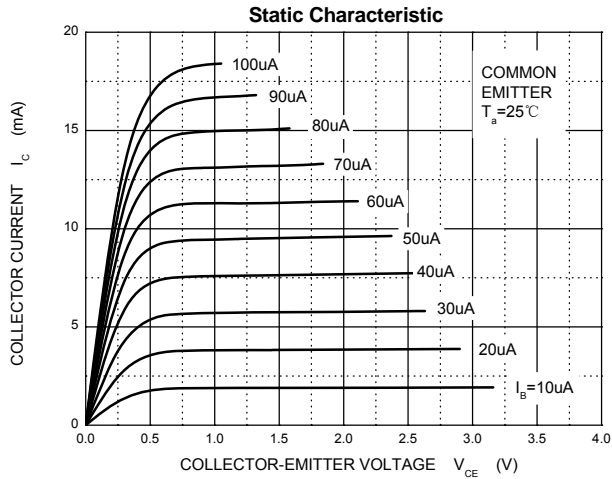
MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current -Continuous	I_C	0.2	A
Power Dissipation	P_d	0.2	W
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}\text{C}$

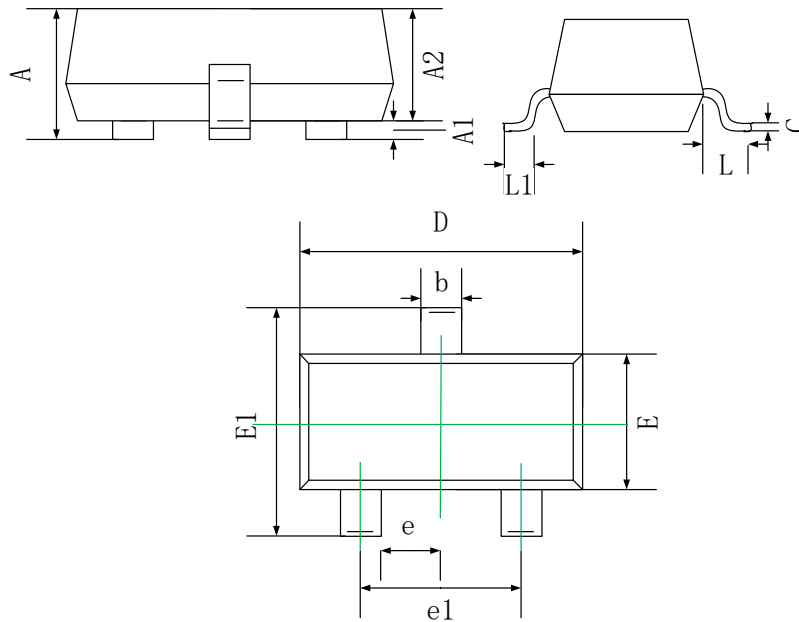
ELECTRICAL CHARACTERISTICS($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	60		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	40		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	6		V
Collector cut-off current	I_{CEO}	$V_{CE}=30\text{V}, I_B=0\text{V}$		100	nA
Base cut-off current	I_{CBO}	$V_{CB}=60\text{V}, I_E=0\text{V}$		100	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=6\text{V}, I_C=0$		100	nA
DC current gain	h_{FE}	$V_{CE}=1\text{V}, I_C=100\mu\text{A}$	40		
		$V_{CE}=1\text{V}, I_C=1\text{mA}$	70		
		$V_{CE}=1\text{V}, I_C=10\text{mA}$	100	300	
		$V_{CE}=1\text{V}, I_C=50\text{mA}$	60		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10\text{mA}, I_B=1\text{mA}$		0.25	V
		$I_C=50\text{mA}, I_B=5\text{mA}$		0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10\text{mA}, I_B=1\text{mA}$		0.85	V
		$I_C=50\text{mA}, I_B=5\text{mA}$		0.95	V
Transition frequency	f_T	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	300		MHZ
Delay time	t_d	$V_{CC}=3\text{V}, V_{BE(off)}=0.5\text{V}, I_C=10\text{mA}, I_{B1}=1\text{mA}$		35	ns
Rise time	t_r			35	ns
Storage time	t_s	$V_{CC}=3\text{V}, I_C=10\text{mA}, I_{B1}=I_{B2}=1\text{mA}$		225	ns
Fall time	t_f			75	ns

Typical Characteristics

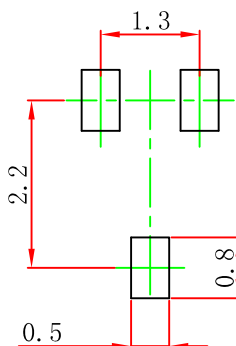


SOT-323 Package Information



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.90	1.10
A1	0.00	0.10
A2	0.90	1.00
b	0.30	0.50
c	0.10	0.15
D	2.00	2.20
E	1.15	1.35
E1	2.15	2.40
e	0.650 TYP.	
e1	1.20	1.40
L	0.525 REF.	
L1	0.26	0.46

SOT-323 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.